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Design of a mixed conductive garnet/Li interface for dendrite-free solid lithium metal batteries?

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Solid-state batteries (SSBs) with metallic lithium (Li) anodes and non-flammable solid-state electrolytes (SSEs) are viewed as the next-generation batteries because of their potential improvement in energy density and guarantee of safety. However, even though the high-density solid garnet SSE pellets exhibit high ionic conductivity, high transference number, and large shear modulus, the unexpectedly serious occurrence of dendrite propagation remains a problem. Herein, a mixed conductive layer (MCL) consisting of electronic conductive nanoparticles embedded in an ionic conductive network is introduced at the interface between the garnet SSE and the Li anode. Such MCL not only leads to the transition of lithiophobicity to lithiophilicity, but also homogenizes the electricfield distribution inside the MCL and relieves the electronic attacks to the garnet. As a result, the Li/MCL/garnet/MCL/Li cells show a critical current density as high as 1.2 mA cm⁻² and stable cycling for over 1000 h at 0.1 mA cm⁻². The LiCoO₂/Li cells with the MCLprotected interface show excellent cycling and rate performances at room temperature. These results demonstrate a rational design for a stable garnet/Li interface and an effective strategy to enable Li metal anodes in SSBs.

The growing demands of smart electronics and electric vehicles underscore the need for new rechargeable batteries with high energy densities. Solid-state batteries (SSBs) are promising candidates. The key materials, solid-state electrolytes (SSEs), have demonstrated the potential to incorporate high-voltage cathodes and high-capacity Li metal anodes, achieving high

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Broader context

The promise to obtain long-lifespan and dendrite-free solid-state batteries (SSBs) with high energy density and high safety is thrilling. As a key component, garnet-type solid-state electrolytes (SSEs) are highly attractive due to their high ionic conductivity at room temperature and high stability against Li metal. However, they are more likely to cause Li dendrite propagation than the conventional liquid electrolytes, leading to rapid short circuiting of SSBs. The relevant mechanism investigation has attracted considerable attention recently. It is generally acknowledged that an ideal SSE/Li interface requires high Li⁺ conductivity but electronic insulation; in particular, the high electronic conductivity of SSEs was reported as evil for short-circuiting the SSBs. However, our research demonstrates a mixed ionic/electronic conductive interface as beneficial for Li dendrite suppression, where electronic conductive nanoparticles are embedded in an ionic conductive network. The built-in electronic pathways can guide a uniform electric field for dendrite-suppressed Li deposition. The SSBs with protected Li anodes show excellent cycling and rate performance in both Li symmetric cells and LiCoO2/Li cells.

energy density for SSBs. In addition, the safety concerns of conventional Li-ion batteries are well addressed by replacing the hazardous liquid electrolytes with inflammable SSEs in

As a key component in SSBs, various types of SSEs have been studied for decades, including perovskite-type,3 sodium superionic conductor (NASICON)-type, 4,5 lithium phosphorus oxynitride (LiPON),6 sulfide-type,7 and garnet-type materials.8 Among them, garnet-type Li₇La₃Zr₂O₁₂ (LLZO) is highly attractive due to its high ionic conductivity at room temperature and the chemical and electrochemical stabilities against Li metal.^{9,10} The partial substitutions of aliovalent cations such as Ta and Nb for the Zr element of LLZO can further improve the ionic conductivity to over 10⁻³ S cm⁻¹. 11,12 However, LLZO shows an even higher tendency to cause Li dendrite formation than the conventional liquid electrolytes, even though the high Li transference number (~ 1), high shear modulus (~ 55 GPa), and high relative density (>99%) of LLZO are supposed to suppress Li dendrites. 13-15

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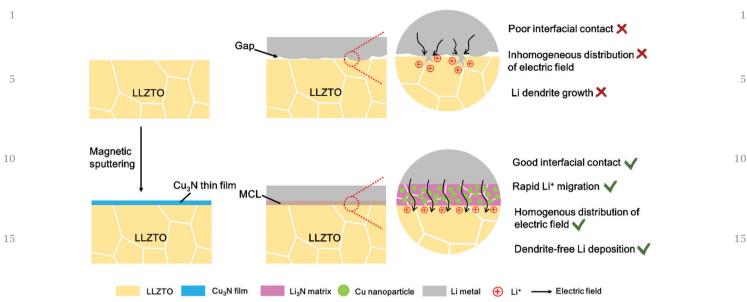
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Scheme 1 The schematic of the mixed conductive intermediate layer (MCL) protected LLZTO/Li interface for dendrite-free Li metal solid batteries.

Although the mechanism of dendrite growth in SSBs still remains unclear, LLZO is well acknowledged as lithiophobic, which causes the point contacts between the Li metal and the SSE and initiates the dendrite nucleation at the interface. 16,17 Once a tiny dendrite forms, the local electrical field will change rapidly. The Li⁺ preferentially deposits on the existing dendrite spots and further propagates in the LLZO bulk through the grain boundaries, voids and other defects, causing short circuiting of the SSBs eventually (Scheme 1).18,19 Therefore, improving the interfacial contact is important to suppress the Li dendrite formation. Various intermediate layers including Al₂O₃, Nb, Si, and Sn have been introduced in between the LLZO and the Li, which indeed enhance the wettability of LLZO with molten Li and thus reduce Li dendrite growth to some extent at low current densities. 20-23 However, at a high current density above 1.0 mA cm⁻², lithium infiltration still occurs. This indicates that the sole improvement of wettability is not sufficient to thoroughly solve the dendrite problem. Recently, Han et al. revealed that the residual electronic conductivity of LLZO ceramic is the origin of dendrite formation in SSBs using neutron depth profiling (NDP).²⁴ Guo et al. pointed out that the injection of electrons could cause precipitation of Li in polycrystalline garnets.²⁵ They further compared the functionality of various intermediate layers and suggested that an ideal intermediate layer should lead to small interfacial resistance, high ionic conductivity but negligible electronic conductivity, and mechanical stability during repetitive cycles.²

It is generally acknowledged that an ideal solid electrolyte interface (SEI) in liquid-based cells and electrode/electrolyte interface in SSBs requires two primary features: high Li⁺ conductivity and electronic insulation.²⁶ The Li⁺ conductivity ensures ionic channels at the electrolyte/Li interface, while the electronic insulation is required to prevent undesired side reactions between the electrolytes and the Li metal anodes. However, due to the solid–solid contact, ensuring interfacial

wettability between the Li metal and the SSE is crucial in SSBs, unlike in liquid-based cells in which the organic liquid electrolytes can readily cover the Li metal surface. An intermediate layer with ionic conductivity alone showed large interfacial resistance, which could not satisfy the long-term cycles of SSBs so far.²¹ A mixed ionic/electronic conductive layer (MCL) with built-in electronic conductivity may alleviate the Li⁺ concentration gradient and level the local current distribution on the Li metal surface, thus leading to homogenous Li deposition.²⁷ The MCL protected Li metal cells with inner electronic channels can render superior cycling performance in liquid-based cells. Zhang et al. reported an armored LiF/Cu-based protective MCL, which renders the cells with reduced impedance and long lifespan. ²⁸ Peng *et al.* also stabilized the electrolyte/Li interface with a MCL based on nanoscale LiF/Ni domains, indicating that the MCLs have a good artificial SEI to protect the Li metal in liquid-based cells.²⁹ This abundant knowledge of liquidelectrolyte based Li metal batteries can be learned from to address the dendrite issue in SSBs. Therefore, it is worth examining the effect of MCLs on Li dendrite suppression at the interface between Li and garnet, where interfacial contacts and electrochemical kinetics remain challenging.

Herein, an *in situ* formed Li₃N/Cu MCL is proposed to modify the LLZO/Li interface by a facile conversion reaction between a Cu₃N thin film and molten Li at 200 °C (Scheme 1). Such an MCL shows a strong wetting interaction with Li metal, substantially decreasing the interfacial resistance from 1138.5 to 83.4 Ω cm² at 25 °C. In addition, it is more stable than Li alloy layers that may be detached from the garnet pellets after hundreds of cycles. The Li₃N as the ionically conducting matrix possesses high Li⁺ conductivity (close to 10^{-3} S cm⁻¹) and low energy barriers for Li⁺ migration (0.007–0.038 eV) at room temperature, which is beneficial for rapid Li⁺ transport across the interface.³⁰ The uniformly dispersed Cu nanoparticles inside the MCL not only guide a homogeneous electronic

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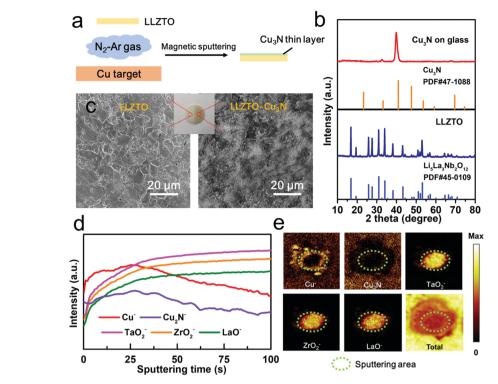


Fig. 1 (a) Schematic illustration of the deposition of Cu_3N film on the LLZTO ceramic pellet. (b) XRD patterns of LLZTO pellet and Cu_3N film on the glass plate. (c) SEM images of LLZTO surfaces with or without Cu_3N deposition. (d) TOF-SIMS depth profiles for the LLZTO- Cu_3N pellet. (e) TOF-SIMS chemical mappings at the end of sputtering.

distribution to suppress the lithium dendrite nucleation but also serve as a supported matrix to alleviate the volume change in case of an Li-defective state. As a proof of concept, lithium plating–stripping behavior exhibits long-term stability in Li symmetric cells and LiCoO_2/Li cells.

As shown in Fig. 1a, the Cu₃N film was prepared on a Tadoped LLZO (LLZTO) pellet by a reactive sputtering method under N2/Ar gas. The LLZTO pellets were prepared by a hotpressing sintering method according to our previous work. 11 All the diffraction peaks in Fig. 1b matched well with the standard pattern of cubic-phase LLZO (PDF#45-0109). The stabilized cubic phase enabled a high ionic conductivity of 1.1×10^{-3} S cm⁻¹ at 25 °C and the relative density of LLZTO was over 99% by hot pressing (Fig. S1, ESI†). The LLZTO pellets were polished to eliminate the Li₂CO₃ surface contaminants before depositing a Cu₃N film. Fig. 1c compares the optical and scanning electron microscope (SEM) images of the LLZTO pellet with or without Cu₃N coating. The bare LLZTO surface exhibited clear polishing scratches with exposed grain boundaries. After coating Cu₃N on LLZTO, the white LLZTO surface turned yellow and was completely covered. The Cu₃N film was also deposited on a glass plate for X-ray diffraction (XRD) analysis to confirm the phase purity. The sharp XRD peak at 40.8° corresponding to Cu₃N (111) indicated good crystallinity and strong preferential orientation of the Cu₃N film (Fig. 1b).³¹

Various thicknesses of Cu_3N films were deposited by adjusting the sputtering time. An optimal sputtering time of 30 s was selected based on the resulting interfacial resistance (Fig. S2,

ESI†). The thickness and homogeneity of the optimized Cu₃N film on LLZTO was characterized by the time-of-flight secondary-ion mass spectrometry (TOF-SIMS) technique. The TOF-SIMS depth profiling reveals the evolution of fragments from the specimen as sputtering proceeds in a negative mode. Here, the Cu and Cu2N fragments represented the Cu3N layer, while TaO²⁻, ZrO²⁻ and LaO⁻ fragments indicated the LLZTO underneath. As shown in Fig. 1d, the Cu⁻ and Cu₂N⁻ signal intensities remained high over the first 25 s of Cs+ sputtering and then gradually declined. Complementarily, signals of the TaO²⁻, ZrO²⁻ and LaO⁻ fragments from the LLZTO were absent initially but leveled up after 25 s of Cs⁺ sputtering. Evidently, a homogeneous layer of Cu₃N was covering the LLZTO pellet, which verifies the SEM results. The thickness of Cu₃N was estimated to be 24 nm according to the sputtering rate of 0.96 nm s^{-1} . Fig. 1e shows the TOF-SIMS mappings of Cu⁻, Cu₂N⁻ TaO²⁻, ZrO²⁻ and LaO⁻ signals after analytical sputtering. A sharp contrast between the Cu₃N and LLZTO distributions was observed, where intense TaO²⁻, ZrO²⁻ and LaO signals were observed from the sputtered region and strong Cu⁻ and Cu₂N⁻ signals across the pristine region. The cross-sectional view of the sputtered volume of LLZTO-Cu₃N again confirmed the uniform coverage of Cu₃N on LLZTO (Fig. S3, ESI†).

The Cu/Li₃N MCL was *in situ* formed by reacting the Cu₃N film with molten Li at 200 $^{\circ}$ C. It should be noted that a high temperature over 300 $^{\circ}$ C will lead to the decomposition of Cu₃N, releasing N₂ gas.³¹ The conversion reaction of Cu₃N to

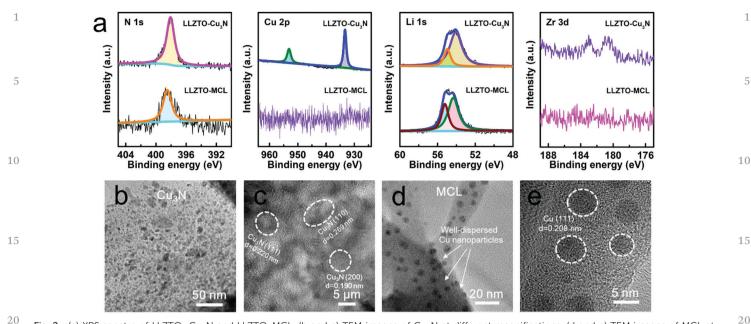


Fig. 2 (a) XPS spectra of LLZTO-Cu $_3$ N and LLZTO-MCL. (b and c) TEM images of Cu $_3$ N at different magnifications. (d and e) TEM images of MCL at different magnifications.

Cu/Li₃N MCL on the surface of the LLZTO pellet was confirmed by X-ray photoelectron spectroscopy (XPS). Fig. 2a shows the N 1s, Cu 2p, Li 1s, and Zr 3d XPS spectra of LLZTO–Cu₃N and LLZTO–MCL. The peaks at the binding energies of 398.0, 953.0, and 933.2 eV were assigned to N 1s, Cu $2p_{1/2}$, and $2p_{3/2}$ excitations, respectively, for Cu₃N. All these Cu₃N related peaks were absent in the XPS spectra of the LLZTO–MCL, indicating a complete reaction. The N 1s peak at 398.0 eV shifted 398.4 eV due to the formation of Li₃N. Two peaks at 54.1 and 55.0 eV in the Li 1s spectra for the LLZTO–Cu₃N pellet can be assigned to the LLZTO substrate and the Li₂CO₃ surface contaminant, respectively. The peak shifting from 54.1 to 54.6 eV could

result from the formation of Li $_3$ N. The peak slightly shifted from 55.0 to 55.1 eV with enhanced intensity due to the residual Li metal covered on the surface. No Cu signal was detected on LLZTO-MCL, which could be ascribed to the Cu nanoparticles that were covered by the Li $_3$ N component. As shown in Fig. S4 (ESI†), the XRD pattern of the formed MCL also confirmed the reaction products of Cu (111) ($2\theta = 43.2^{\circ}$) and Li $_3$ N ($2\theta = 36.7^{\circ}$, 51.2° and 52.4°). The Li $_2$ CO $_3$ peak was presumably due to the short exposure to air.

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Transmission electron microscopy (TEM) was used to further investigate the microstructure and compositional distribution of the MCL. In agreement with the XRD result,

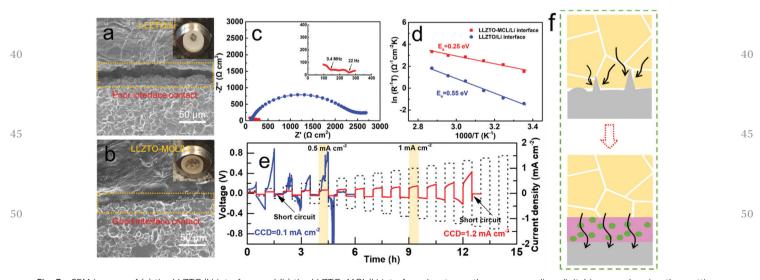


Fig. 3 SEM images of (a) the LLZTO/Li interface and (b) the LLZTO-MCL/Li interface. Insets are the corresponding digital images showing the wetting behaviors of molten Li on bare LLZTO or LLZTO-MCL. (c) EIS spectra, (d) E_a, and (e) CCD of the Li/LLZTO/Li and the Li/LLZTO-MCL/Li cells. (f) Mechanism of increased CCD by MCL.

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crystalline Cu_3N was shown in Fig. 2b and c. The Cu_3N film was actually composed of numerous nano-spherical Cu_3N crystal grains with the size of 5–10 nm. The inter-planar spacings of 0.220, 0.269 and 0.190 nm corresponded to the (111), (110), and (201) planes, respectively. After reacting with molten Li, the crystalline Cu_3N turned into a Li_3N network with Cu nanoparticles evenly dispersing inside (Fig. 2d). The inter-planar spacing of 0.208 nm corresponded to the Cu phase as highlighted in Fig. 2e. The uniform dispersion of Cu nanoparticles in the MCL may be beneficial for guiding a homogeneous electronic flux at the LLZTO/Li interface and effectively suppressing Li dendrite nucleation. 32

The LLZTO-MCL/Li interface was evaluated by investigating the wettability between LLZTO-MCL and molten Li. As shown in Fig. 3a, the pure LLZTO pellet exhibited a lithiophobic nature with Li metal. Flowable molten Li can easily roll into a liquid sphere on the LLZTO surface, showing a large contact angle. The poor wetting behavior consequently led to micro gaps at the interface, as shown in Fig. 3a. In contrast, an intimate contact was observed between the LLZTO-MCL and the Li metal layer without any micro gaps at the interface (Fig. 3b). This could significantly lower the interfacial resistance and improve the electrochemical performance.

The symmetric cells of Li/LLZTO-MCL/Li and Li/LLZTO/Li were assembled for electrochemical characterization. Electrochemical impedance spectroscopy (EIS) was used to compare the interfacial resistance of cells with or without MCL modification on LLZTO. Fig. 3c shows the Nyquist plots obtained at 25 °C. The Nyquist plot of the Li/LLZTO/Li cell exhibited one huge semicircle ascribed to the large interfacial resistance between LLZTO and Li metal. The initial point of the spectra corresponds to the resistance from the bulk LLZTO pellet. Considering charge transfer across the two Li/LLZTO interfaces in one symmetric cell, the interfacial resistance determined from the semicircle was divided by two to obtain the value of each Li/LLZTO interface. Thus, the resistance of a single LLZTO/Li interface was 1138.5 Ω cm². Different from the bare LLZTO cell, the Li/LLZTO-MCL/Li symmetric cell exhibited multiple semicircles resulting from the MCL bulk and the MCL/LLZTO interface at high frequency and the MCL/Li interface at low frequency. The overall resistance of the LLZTO-MCL/Li interface due to the MCL modification was 83.4 Ω cm^{2,21} The significant decrease in interfacial resistance from 1138.5 to 83.4 Ω cm² could be attributed to the lithiophilic property of MCL by a conversion reaction. The MCL even exhibited a lower interfacial resistance than the pure Li₃N layer (175 Ω cm²) reported previously, ³⁴ further confirming the advantage of MCL. In addition, the temperature dependent interfacial resistance evolution was measured from 25 °C to 75 °C, showing good Arrhenius behavior. The activation energy (E_a) of the MCL modified or unmodified interface was calculated by the Arrhenius law, giving a value of 0.25 eV for the LLZTO-MCL/Li interface and 0.55 eV for the LLZTO/Li interface (Fig. 3d and Fig. S5, ESI†). The decreased interfacial E_a can be ascribed to the high ionic conductivity and low energy barrier of Li migration of Li₃N in MCL.²⁶ This can be beneficial for rapid Li⁺ transport across the interface for high rate performance.

Critical current density (CCD) is a key parameter to characterize the stability of the LLZTO/Li interface and effectiveness of Li dendrite suppression. The applied current density was increased from 0.1 to 1.5 mA cm⁻² with a step increase of 0.1 mA cm⁻² per hour (0.5 h stripping and 0.5 h plating) at 25 °C. The CCD was defined as the current density at which the cell was short circuited. As shown in Fig. 3e, the CCD of the Li/ LLZTO/Li cell was only 0.1 mA cm⁻² due to the poor interface, while the CCD of the Li/LLZTO-MCL/Li cell was substantially improved to 1.2 mA cm⁻². The voltage profile of the Li/LLZTO-MCL/Li cell remained smooth and stable before the sudden occurrence of short circuiting. The significant improvement of CCD was a result of the combined contributions from the ionic conductive Li₃N network and the electronic conductive Cu nanoparticles of the MCL. More specifically, the Li₃N matrix provided smooth pathways for rapid Li⁺ transport, and the welldispersed Cu nanoparticles helped to guide a uniform electric field for dendrite-suppressed Li deposition (Fig. 3f). To our best knowledge, the CCD of 1.2 mA cm⁻² is the highest value obtained in garnet-based SSBs (Table S1, ESI†). Even though many surface modification methods helped to decrease the interfacial resistance, the CCD was still limited by the poor interfacial Li⁺ conductivity and interfacial stability at high current densities.

In order to further demonstrate the homogenized electric-field distribution induced by the MCL for Li dendrite suppression, calculated current densities of LLZTO/Li dendrite and LLZTO-MCL/Li dendrite are illustrated in Fig. 4. The LLZTO/Li dendrite showed an inhomogeneously distributed current density. The maximum current density was obtained at the tip of the dendrite. While the current density in LLZTO-MCL/Li dendrite was homogeneous, and it was three orders of magnitude lower than that at the tip of Li dendrite in contact with LLZTO. This result showed that the decreased resistivity by MCL leads to a charge smearing in the Li dendrite, which can effectively suppress the needle-like morphology growth of the Li metal.

Galvanostatic cycling tests were carried out to evaluate the long-term stability of Li⁺ transport across the interface. As shown in Fig. 5a, the Li/LLZTO/Li cell readily showed an

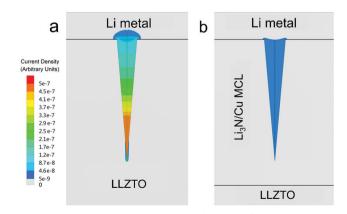


Fig. 4 Calculated current densities for (a) LLZTO/Li dendrite and (b) LLZTO-MCL/Li dendrite.

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inclined overpotential up to 0.29 V at the first plating/stripping cycle at 0.1 mA cm⁻² (0.05 mA h cm⁻²), indicating uneven Li deposition and dissolution. A rapid short circuit occurred within 8 cycles. The poor LLZTO/Li contact and the large interfacial resistance induced inhomogeneous current distribution and local hot spots for Li⁺ flux at the defects, leading to the dendrite growth. 12 After disassembling the short-circuited cell and removing the Li metal electrodes by sanding, the Li dendrites grown into the LLZTO pellet were optically visualized as dark spots on the white LLZTO surface (Fig. S6a, ESI†). This was confirmed by SEM (Fig. S6b and c, ESI†). The crosssectional SEM image along with energy dispersion spectrum (EDS) elemental mappings clearly showed the propagation of Li dendrites along the LLZTO grain boundaries (Fig. 5b and c), which caused short circuiting of the cell. As a note, the SEM specimen was exposed to air briefly during the transfer to the SEM, so the C and O elements were rich at the dendrite locations due to Li₂CO₃. In great contrast, the Li/LLZTO-MCL/ Li cell maintained stable cycling over 1000 h with a smooth overpotential plateau of 30.1 mV at 0.1 mA cm⁻² (Fig. 5d). Very similar overall resistances of 312.4 and 323.3 Ω cm² were maintained before and after cycling, respectively. The optical image showed an all-white LLZTO surface without dark spots of dendrites after sanding (Fig. S7, ESI†). These again indicated the stable interface between the LLZTO-MCL and Li metal anode. Moreover, as shown in Fig. S8 (ESI†), the Li/LLZTO-MCL/Li cells maintained stability over hundreds of hours even with a higher areal capacity of 0.2 mA h cm⁻² at various current densities of 0.1, 0.2, and 0.5 mA cm⁻². The superior performance of LLZTO-MCL compared to other surface-modified LLZTO was attributed to dendrite-free Li deposition and long-term interfacial stability (Table S1, ESI†).

Full SSBs with a Li metal anode and a LiCoO₂ (LCO) cathode were constructed using LLZTO-MCL in comparison with bare LLZTO. Fig. S9 (ESI†) shows the schematic configuration of the SSBs. The composite cathode was prepared using ionic liquid as the wetting agent and super P as the conductive additive for room-temperature feasibility. In agreement with the reduced interfacial resistance by the MCL modification, the overall impedance of the Li/LLZTO-MCL/LCO cell (1029.2 Ω cm² at

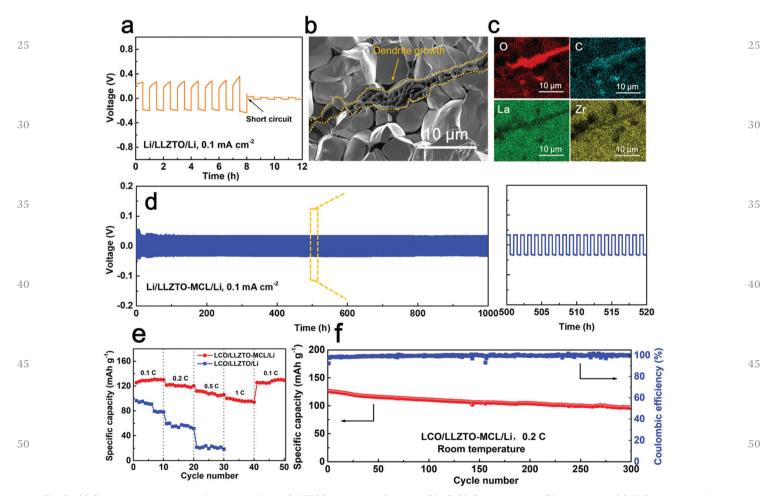


Fig. 5 (a) Galvanostatic cycling performance of the Li/LLZTO/Li cell under 0.1 mA at 25 °C. (b) Cross-sectional SEM image and (c) EDS mappings of the LLZTO pellet collected after cell short circuiting. (d) Galvanostatic cycling performance of the Li/LLZTO-MCL/Li cell under 0.1 mA at 25 °C. (e) Rate performance of the Li/LLZTO/LCO and the Li/LLZTO-MCL/LCO cells. (f) Cycle performance of the Li/LLZTO-MCL/LCO cell under 0.2 C at room temperature.

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25 °C) was smaller than that of the Li/LLZTO/LCO cell (3354.7 Ω cm²) (Fig. S10, ESI†). Correspondingly, the Li/LLZTO-MCL/LCO cell showed smaller polarizations than the Li/LLZTO/LCO cell at different current rates (Fig. S11, ESI†). The LLZTO-MCL cell delivered an initial specific discharge capacity of 130.0 mA h g-1 with a Coulombic efficiency of 91.3% at 0.1 C. The discharge capacities were 125.3, 115.5 and 104.0 mA h g^{-1} at 0.2, 0.5 and 1 C, respectively (Fig. 5e). After high-rate cycling, the cell recovered a discharge capacity of 123.4 mA h g⁻¹ at 0.1 C. The high capacity and excellent rate performance could be attributed to the good interface contact and high mixed ionic/electronic conductivities at the interface. In contrast, the bare LLZTO cell with a less favorable Li interface delivered a discharge capacity of 88.3 mA h g⁻¹ with a high overpotential at 0.1 C. The discharge capacity decreased to 49.7 and 18.9 mA h g^{-1} at 0.2 and 0.5 C, respectively (Fig. 5e). Moreover, the SSB with LLZTO-MCL maintained a high capacity retention of 81.1% after 300 cycles under 0.2 C at room temperature (Fig. 5f).

Conclusions

In summary, a Li₃N/Cu MCL is constructed at the interface between a Li metal anode and a garnet SSE. The interfacial resistance dramatically decreases from 1138.5 to 83.4 Ω cm² at 25 °C as the result of the conversion reaction. The Li₃N matrix in the MCL provides efficient ion-conducting pathways for Li⁺, while the well dispersed Cu nanoparticles guided a homogenous electric field at the interface. The synergistic effect of the external ionic conductivity and internal electronic conductivity relieves the attacks of electrons to the garnet SSE, thus suppressing Li dendrite nucleation. The resulting CCD of the MCLprotected Li symmetrical cell is as high as 1.2 mA cm⁻². The cells exhibit stable cycling over 1000 h with a low overpotential of 30.1 mV under 0.1 mA cm⁻². The LCO/Li cell with LLZTO-MCL maintains a high capacity retention of 81.1% after 300 cycles under 0.2 C at 25 °C. This superior electrochemical performance clearly indicates the effectiveness of the designed MCL for depressing Li propagation into the garnet SSEs. This work sheds light on the rational design of an excellent interface between the Li metal anode and the SSE, affording the feasibility to obtain long-lifespan and dendrite-free SSBs with high energy density and high safety.

Conflicts of interest



Acknowledgements

H. H. conceived and designed the experimental work and prepared the manuscript; Y. C. did the sputtering and TEM characterizations; R. L. helped with the SEM characterizations; Dr N. Z. fabricated the garnet ceramic pellets. J. L. polished the language. J. G. P. S., R. M., and P. K. did the simulations.

X. G., and X. S. supervised the overall project. All authors have given approval to the final version of the manuscript. The authors would like to thank the National Natural Science Foundation of China (Grant No. 51771222, 51532002, 51772314 and 51702346), the National Key R&D Program of China (Grant No. 2018YFB0104300), the "Taishan Scholars Program", Natural Sciences and Engineering Research Council of Canada (NSERC), Canada Research Chair Program (CRC), and University of Western Ontario.

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